

BB301M

Built in Biasing Circuit MOS FET IC VHF RF Amplifier

REJ03G0824-0300 (Previous ADE-208-506A) Rev.3.00 Aug.10.2005

Features

- Built in Biasing Circuit; To reduce using parts cost & PC board space.
- Low noise characteristics; (NF = 1.3 dB typ. at f = 200 MHz)
- Withstanding to ESD;
- Built in ESD absorbing diode. Withstand up to 200V at C=200pF, Rs=0 conditions.
- Provide mini mold packages; MPAK-4(SOT-143Rmod)

Outline

RENESAS Package code: PLSP0004ZA-A (Package name: MPAK-4)



- 1. Source
- 2. Gate1
- 3. Gate2
- 4. Drain

Notes: 1. Marking is "AW-".

2. BB301M is individual type number of RENESAS BBFET.



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

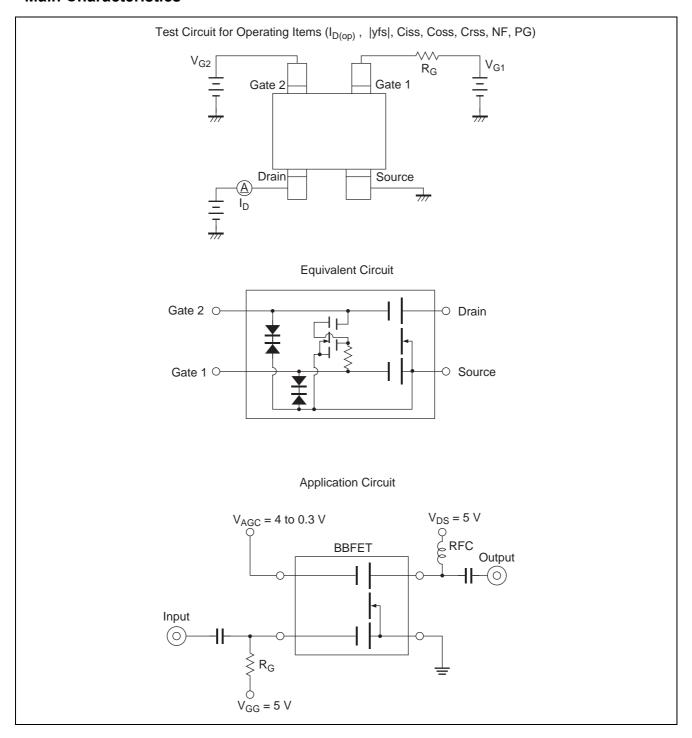
Item	Symbol	Ratings	Unit
Drain to source voltage	V _{DS}	6	V
Gate1 to source voltage	V _{G1S}	+6	V
		-0	
Gate2 to source voltage	V _{G2S}	±6	V
Drain current	I _D	25	mA
Channel power dissipation	Pch	150	mW
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

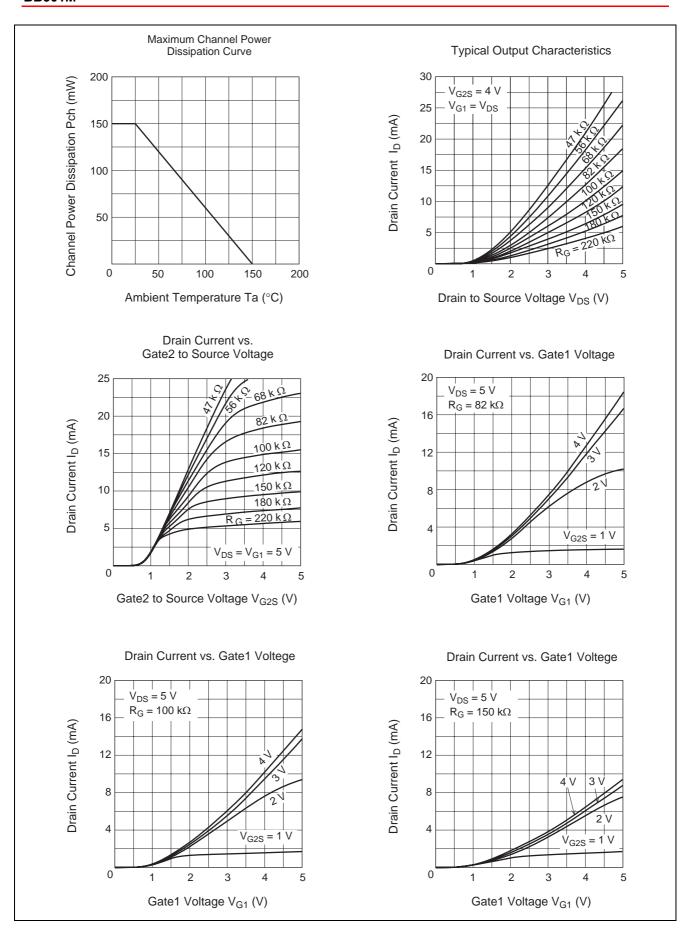
Electrical Characteristics

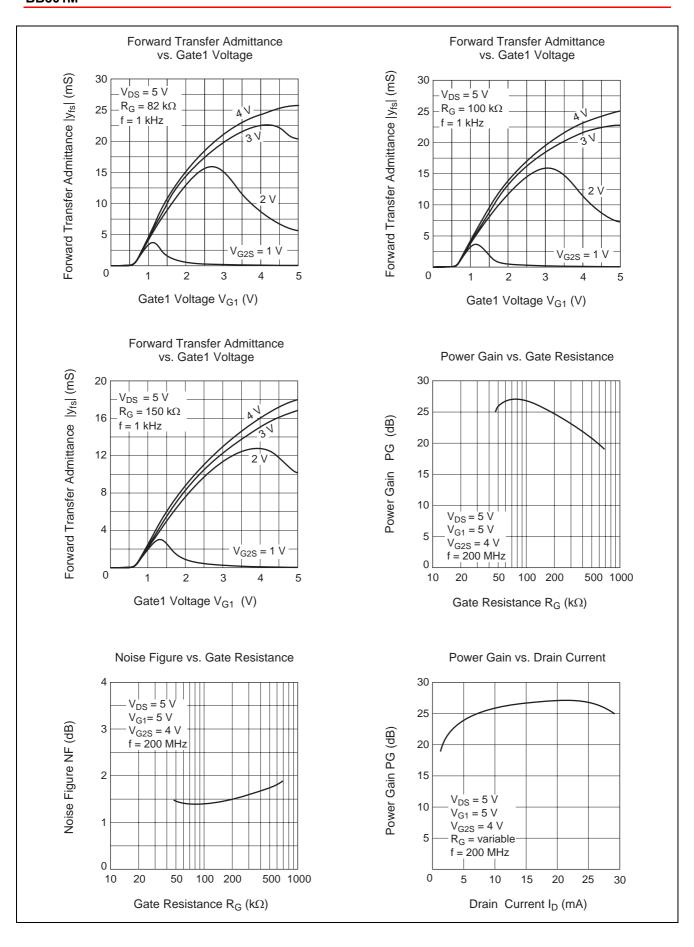
 $(Ta = 25^{\circ}C)$

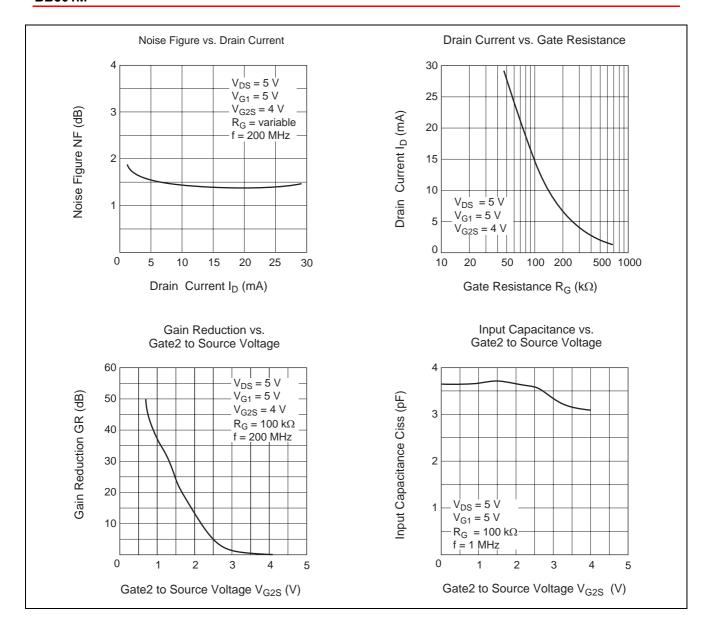
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Drain to source breakdown voltage	V _{(BR)DSS}	6	_	_	V	$I_D = 200 \ \mu A, \ V_{G1S} = V_{G2S} = 0$
Gate1 to source breakdown voltage	$V_{(BR)G1SS}$	+6	_	_	V	$I_{G1} = +10 \mu A, V_{G2S} = V_{DS} = 0$
Gate2 to source breakdown voltage	$V_{(BR)G2SS}$	±6	_	_	V	$I_{G2} = \pm 10 \ \mu A, \ V_{G1S} = V_{DS} = 0$
Gate1 to source cutoff current	I _{G1SS}	_	_	+100	nA	$V_{G1S} = +5 \text{ V}, V_{G2S} = V_{DS} = 0$
Gate2 to source cutoff current	I _{G2SS}	_	_	±100	nA	$V_{G2S} = \pm 5 \text{ V}, V_{G1S} = V_{DS} = 0$
Gate1 to source cutoff voltage	$V_{G1S(off)}$	0.4	_	1.0	V	$V_{DS} = 5 \text{ V}, V_{G2S} = 4 \text{ V}$
						$I_D = 100 \mu A$
Gate2 to source cutoff voltage	$V_{G2S(off)}$	0.4	_	1.0	V	$V_{DS} = 5 \text{ V}, V_{G1S} = 5 \text{ V}$
						I _D = 100 μA
Drain current	$I_{D(op)}$	10	15	20	mA	$V_{DS} = 5 \text{ V}, V_{G1} = 5 \text{ V}$
						$V_{G2S} = 4 \text{ V}, R_G = 100 \text{ k}\Omega$
Forward transfer admittance	y _{fs}	15	20	_	mS	$V_{DS} = 5 \text{ V}, V_{G1} = 5 \text{ V}, V_{G2S} = 4 \text{ V}$
						$R_G = 100 \text{ k}\Omega, f = 1 \text{ kHz}$
Input capacitance	Ciss	2.2	3.0	3.9	pF	$V_{DS} = 5 \text{ V}, V_{G1} = 5 \text{ V}$
Output capacitance	Coss	0.9	1.2	1.6	pF	$V_{G2S} = 4 \text{ V}, R_G = 100 \text{ k}\Omega$
Reverse transfer capacitance	Crss		0.018	0.04	pF	f = 1 MHz
Power gain	PG	22	26		dB	$V_{DS} = 5 \text{ V}, V_{G1} = 5 \text{ V}, V_{G2S} = 4 \text{ V}$
Noise figure	NF	_	1.3	1.9	dB	$R_G = 100 \text{ k}\Omega, \ f = 200 \text{ MHz}$

Main Characteristics

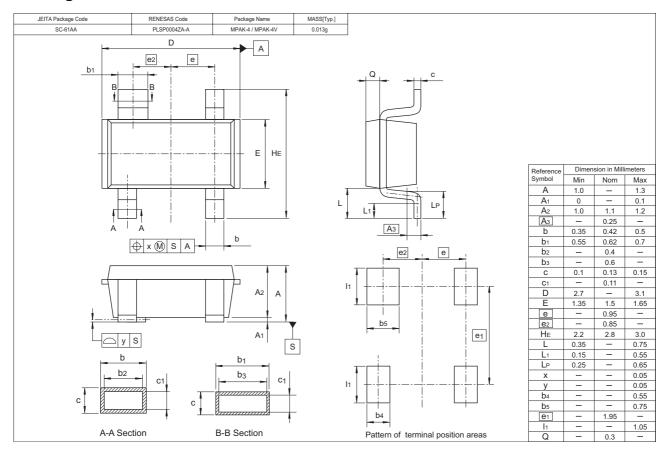








Package Dimensions



Ordering Information

Part Name	Quantity	Shipping Container
BB301MAW-TL-E	3000	φ 178 mm Reel, 8 mm Emboss Taping

Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.

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